

### Nch 50V 200mA Small Signal MOSFET

V <sub>DSS</sub>	50V
R <sub>DS(on)</sub> (Max.)	$2.2\Omega$
I <sub>D</sub>	200mA
$P_D$	150mW

RE1J002YN

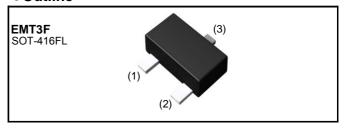
#### Features

- 1) Low voltage drive(0.9V) makes this device ideal for partable equipment.
- 2) Drive circuits can be simple.
- 3) Built-in G-S Protection Diode.

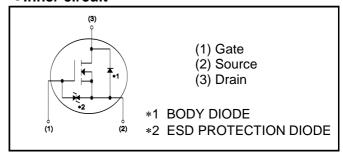
### Application

Switching

#### Outline



#### •Inner circuit



Packaging specifications

	<del></del>	
	Packaging	Taping
	Reel size (mm)	180
Type	Tape width (mm)	8
Type	Basic ordering unit (pcs)	3,000
	Taping code	TL
	Marking	QJ

### ● Absolute maximum ratings(T<sub>a</sub> = 25°C)

Parameter	Symbol	Value	Unit
Drain - Source voltage	$V_{DSS}$	50	V
Continuous drain current	I <sub>D</sub> <sup>*1</sup>	±200	mA
Pulsed drain current	I <sub>D,pulse</sub> *2	±800	mA
Gate - Source voltage	$V_{GSS}$	±8	V
Power dissipation	P <sub>D</sub> *3	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### ●Thermal resistance

Parameter	Symbol	Values			Lloit
Farameter		Min.	Тур.	Max.	Unit
Thermal resistance, junction - ambient	R <sub>thJA</sub> *3	-	-	833	°C/W

# •Electrical characteristics( $T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai ii e lei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$ , $I_D = 1mA$	50	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 50V, V_{GS} = 0V$	ı	ı	1	μΑ
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 8V, V_{DS} = 0V$	ı	1	±10	μΑ
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = 10V$ , $I_D = 1mA$	0.3	ı	0.8	V
	R <sub>DS(on)</sub> *4	V <sub>GS</sub> =4.5V, I <sub>D</sub> =200mA	ı	1.6	2.2	
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =200mA	-	1.7	2.4	
Static drain - source		V <sub>GS</sub> =1.5V, I <sub>D</sub> =200mA	-	2.0	2.8	0
on - state resistance		V <sub>GS</sub> =1.2V, I <sub>D</sub> =100mA	-	2.2	3.3	Ω
		$V_{GS}$ =0.9V, $I_D$ =10mA	-	3.0	9.0	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =200mA, T <sub>j</sub> =125°C	-	2.7	3.8	
Transconductance	g <sub>fs</sub> *4	V <sub>DS</sub> =10V, I <sub>D</sub> =200mA	200	-	-	mS

<sup>\*1</sup> Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*3</sup> Each therminal mounted on a recommended land

<sup>\*4</sup> Pulsed

# •Electrical characteristics( $T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai ii e lei	Symbol Conditions —		Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0V$	-	26	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 10V	-	6	-	pF
Reverse transfer capacitance	$C_{rss}$	f = 1MHz	-	3	-	
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 25V, V_{GS} = 4.5V$	-	5	-	
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 100mA	-	8	-	no
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L = 249\Omega$	-	17	-	ns
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$	-	43	-	

### ●Body diode electrical characteristics (Source-Drain)(T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
r arameter	Symbol		Min.	Тур.	Max.	Offic
Continuous source current	I <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	-	125	mA
Pulsed source current	I <sub>SM</sub> *2	1 <sub>c</sub> = 23 C	-	-	800	mA
Forward voltage	V <sub>SD</sub> *4	$V_{GS} = 0V, I_s = 200 \text{mA}$	-	-	1.2	V

Fig.1 Power Dissipation Derating Curve

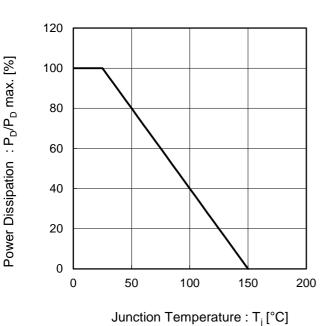


Fig.2 Drain Current Derating Curve

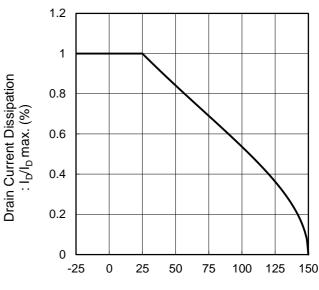
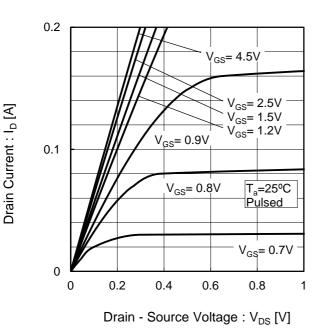


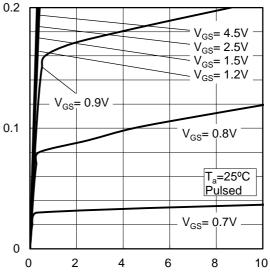
Fig.3 Typical Output Characteristics(I)



Drain Current: I<sub>D</sub> [A]

Fig.4 Typical Output Characteristics(II)

Junction Temperature : T<sub>i</sub> [°C]



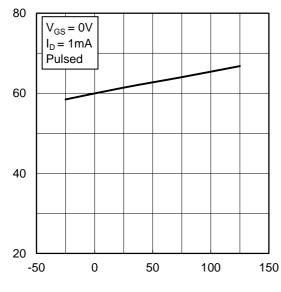
Drain - Source Voltage : V<sub>DS</sub> [V]

Drain - Source Breakdown Voltage: V<sub>(BR)DSS</sub> [V]

Gate Threshold Voltage: V<sub>GS(th)</sub> [V]

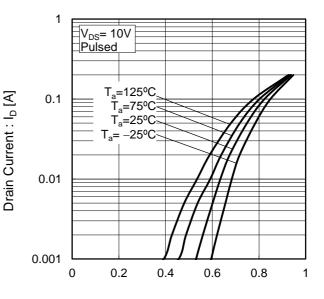
#### •Electrical characteristic curves

Fig.5 Breakdown Voltage vs. Junction Temperature



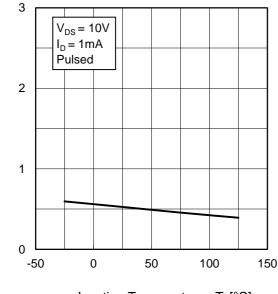
Junction Temperature : T<sub>i</sub> [°C]

Fig.6 Typical Transfer Characteristics



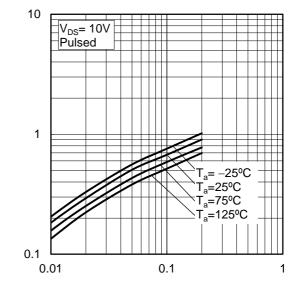
Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.7 Gate Threshold Voltage vs. Junction Temperature



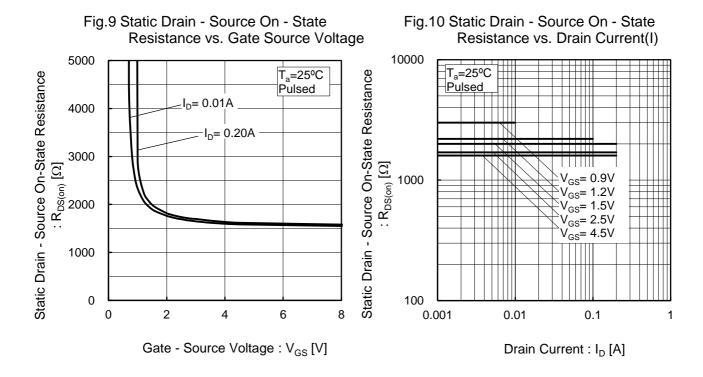
Junction Temperature : T<sub>i</sub> [°C]

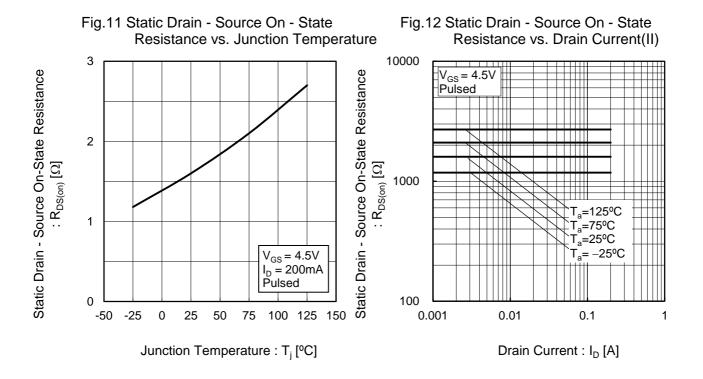
Fig.8 Transconductance vs. Drain Current

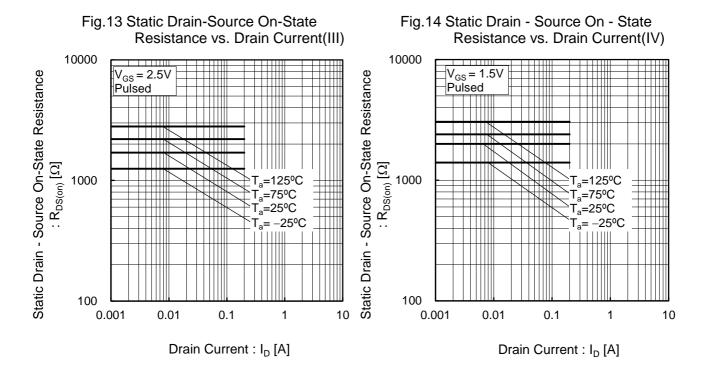


Drain Current : I<sub>D</sub> [A]

Transconductance: gfs [S]







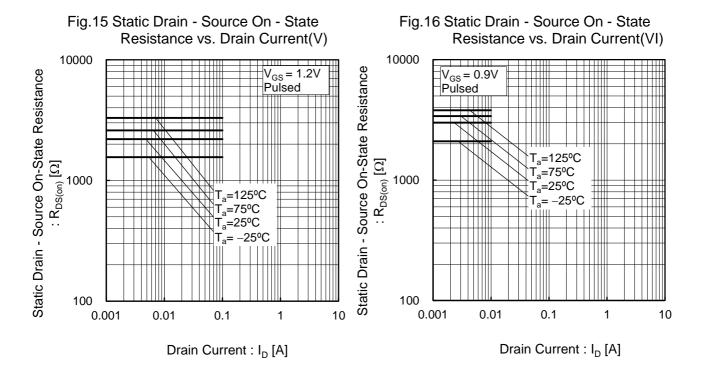
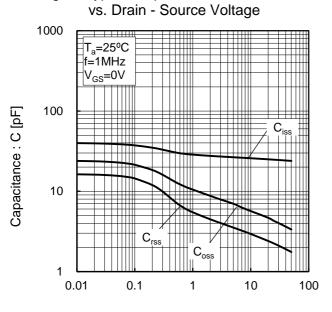
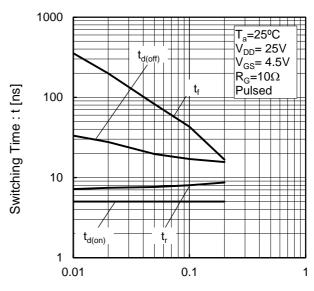


Fig.17 Typical Capacitance



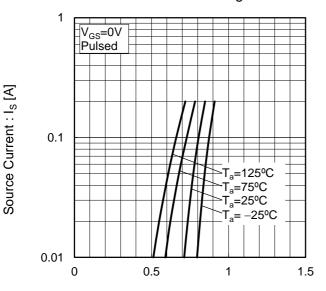
Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.18 Switching Characteristics



Drain Current : I<sub>D</sub> [A]

Fig.19 Source Current vs. Source Drain Voltage



Source-Drain Voltage :  $V_{SD}$  [V]

### ● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

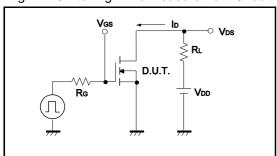
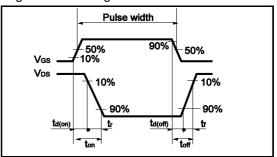
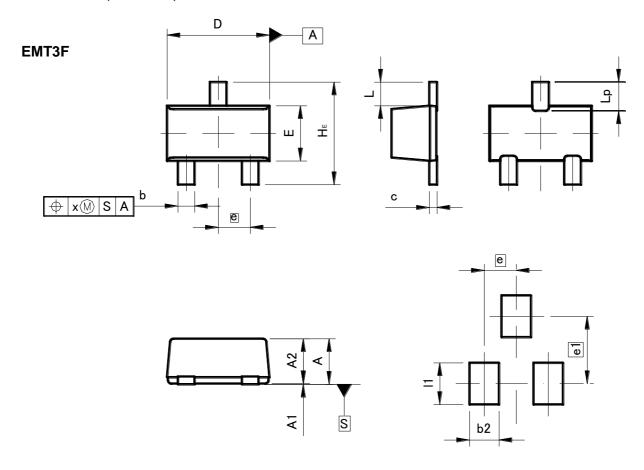


Fig.1-2 Switching Waveforms



### ●Dimensions (Unit:mm)



Patterm of terminal position areas

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	0.65	0.85		
A1	0.00	0.10	0	0.004
A2	0.60	0.80	0.024	0.031
b	0.21	0.36	0.008	0.014
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	0.76	0.96	0.03	0.038
е	0.9	50	0.0	02
HE	1.50	1.70	0.059	0.067
L	0.0	37	0.0	15
Lp	0.35	0.55	0.014	0.022
х	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	-	1.05	-	0.041	
b2	-	0.46	-	0.018	
	_	0.65	_	0.026	

Dimension in mm/inches

#### Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

# ROHM Customer Support System

http://www.rohm.com/contact/